TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74VHC86F, TC74VHC86FN, TC74VHC86FT

QUAD EXCLUSIVE OR GATE

The TC74VHC86 is an advanced high speed CMOS QUAD EXCLUSIVE OR GATE fabricated with silicon gate C2MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

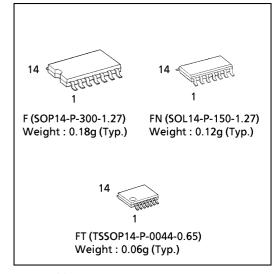
The internal circuit is includes on output buffer, which provide high noise immunity and stable output.

An Input protection circuit ensures that 0 to 5.5V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and on two supply system such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

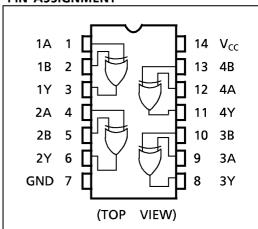
FEATURES:

- High Speed······ t_{pd} = 4.8ns(typ.) at V_{CC} = 5V
- High Noise Immunity..... $V_{NIH} = V_{NII} = 28\% V_{CC}$ (Min.)
- Power Down Protection is provided on all inputs.
- Balanced Propagation Delays $\cdots t_{pLH} \simeq t_{pHL}$
- Wide Operating Voltage Range \cdots V_{CC} (opr) = $2V \sim 5.5V$
- Low NoiseV_{OLP} = 0.8V (Max.)
- Pin and Function Compatible with 74ALS86

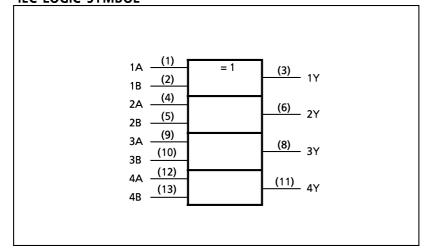
(Note) The JEDEC SOP (FN) is not available in Japan.



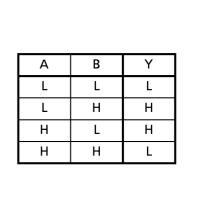
PIN ASSIGNMENT



IEC LOGIC SYMBOL



TRUTH TABLE



ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V _{cc}	-0.5~7.0	V
DC Input Voltage	V _{IN}	-0.5~7.0	V
DC Output Voltage	V _{OUT}	$-0.5 \sim V_{CC} + 0.5$	٧
Input Diode Current	I _{IK}	-20	mA
Output Diode Current	I _{OK}	± 20	mA
DC Output Current	I _{OUT}	± 25	mA
DC V _{CC} /Ground Current	I _{CC}	± 50	mA
Power Dissipation	P _D	180	mW
Storage Temperature	T _{stg}	−65~150	°C

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V _{cc}	2.0~5.5	>
Input Voltage	VIN	0~5.5	٧
Output Voltage	V _{OUT}	0~V _{cc}	٧
Operating Temperature	T _{opr}	−40~85	°C
Input Rise and Fall Time	dt/dv	$0\sim100 \ (V_{CC} = 3.3 \pm 0.3 V)$ $0\sim20 \ (V_{CC} = 5 \pm 0.5 V)$	ns / V

DC ELECTRICAL CHARACTERISTICS

PARAMETER SYMBOL		TEST CONDITION		V _{CC}	Ta = 25°C			Ta = −40~85°C		UNIT
				(V)	MIN.	TYP.	MAX.	MIN.	MAX.	UNIT
High - Level	V _{IH}			2.0 3.0~ 5.5	1.50	_	_	1.50	1	<
Input Voltage	- 111				$V_{cc} \times 0.7$	_	_	$V_{cc} \times 0.7$	_	
Low - Level	.,				_	_	0.50	_	0.50	
Input Voltage	V _{IL}			3.0~ 5.5	_	-	$V_{cc} \times 0.3$	_	$V_{cc} \times 0.3$	V
High - Level Output Voltage	.,	V _{I N} =	$I_{OH} = -50\mu A$	2.0	1.9 2.9	2.0 3.0	_	1.9 2.9		V
	V _{OH}	V _{IH} or V _{IL}		4.5	4.4	4.5	_	4.4	_	V
		VIH OI VIL	$I_{OH} = -4mA$ $I_{OH} = -8mA$	3.0 4.5	2.58 3.94	_	_	2.48 3.80	_	
Low - Level Output Voltage	V _{1 N} =	$I_{OL} = 50 \mu A$	2.0 3.0 4.5	111	0.0 0.0 0.0	0.1 0.1 0.1		0.1 0.1 0.1	V	
		V _{IH} or V _{IL}	$I_{OL} = 4mA$ $I_{OL} = 8mA$	3.0 4.5	1 1	_	0.36 0.36		0.44 0.44	
Input Leakage Current	I _{IN}	$V_{IN} = 5.5V$ or GND		0~5.5	_	_	± 0.1	_	± 1.0	
Quiescent Supply Current	I _{cc}	$V_{IN} = V_{CC}$ or GND		5.5	_	_	2.0	_	20.0	μ A

PARAMETER	SYMBOL	TEST CONDITION		Ta = 25°C			Ta = -40~85°C		UNIT	
			V _{CC} (V)	CL (pF)	MIN.	TYP.	MAX.	MIN.	MAX.	ONIT
Propagation Delay Time	t _{pLH} t _{pHL}		3.3 ± 0.3	15	_	7.0	11.0	1.0	13.0	ns
				50	_	9.5	14.5	1.0	16.5	
			5.0 ± 0.5	15	_	4.8	6.8	1.0	8.0	
				50	_	6.3	8.8	1.0	10.0	
Input Capacitance	C _{I N}				_	4	10	_	10	pF
Power Dissipation Capacitance	C _{PD}	(Note 1)		_	18	_	_	_	рΓ

Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

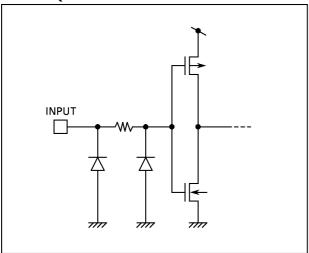
Average operating current can be obtained by the equation:

$$I_{CC(opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 4 \text{ (per Gate)}$$

NOISE CHARACTERISTICS (Input $t_r = t_f = 3ns$)

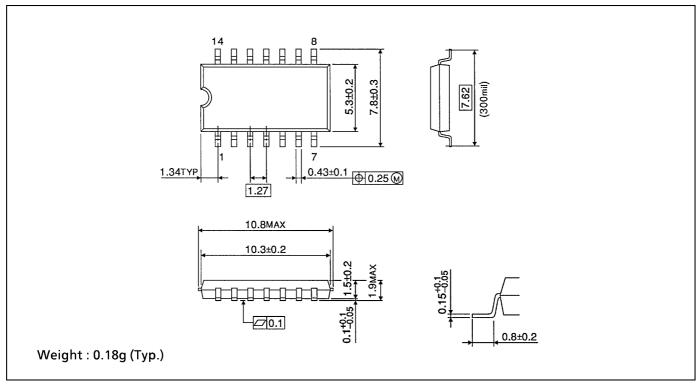
PARAMETER	SYMBOL	TEST CONDIT	Ta =	UNIT		
			V _{cc} (V)	TYP.	LIMIT	UNIT
Quiet Output Maximum Dynamic V _{OL}	V _{OLP}	$C_L = 50pF$	5.0	0.3	0.8	\ \
Quiet Output Minimum Dynamic V _{OL}	V _{OLV}	$C_L = 50pF$	5.0	-0.3	-0.8	>
Minimum High Level Dynamic Input Voltage	V _{IHD}	$C_L = 50pF$	5.0	_	3.5	<
Maximum Low Level Dynamic Input Voltage	V _{ILD}	C _L = 50pF	5.0	-	1.5	>

INPUT EQUIVALENT CIRCUIT



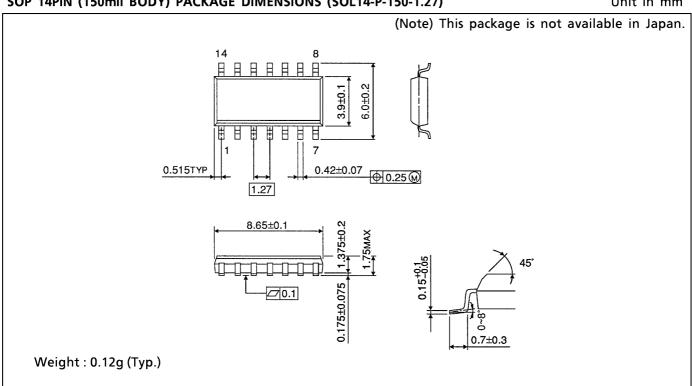
SOP 14PIN (200mil BODY) PACKAGE DIMENSIONS (SOP14-P-300-1.27)

Unit in mm



SOP 14PIN (150mil BODY) PACKAGE DIMENSIONS (SOL14-P-150-1.27)

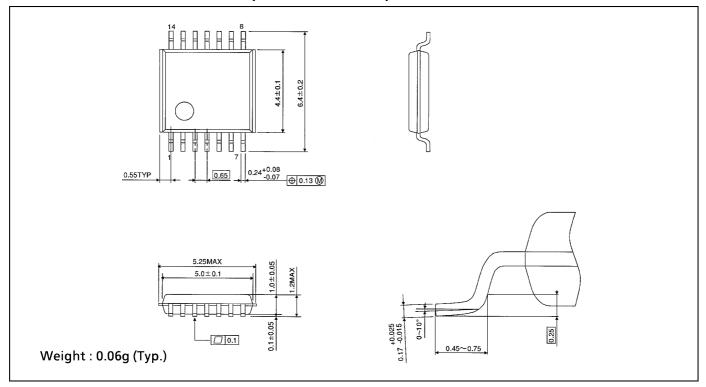
Unit in mm



4

TSSOP 14PIN PACKAGE DIMENSIONS (TSSOP14-P-0044-0.65)

Unit in mm



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